

## SANYO Semiconductors DATA SHEET

### N-Channel Silicon MOSFET

# **CPH3423**—General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		1.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	6	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =0.75A	0.75	1.5		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =0.75A, V <sub>G</sub> S=10V		240	310	mΩ
	RDS(on)2	ID=0.75A, VGS=4V		320	450	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		150		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		19.0		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		13.0		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		7		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		3		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		20		ns
Fall Time	tf	See specified Test Circuit.		11		ns

Marking: KY

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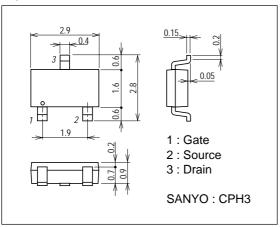
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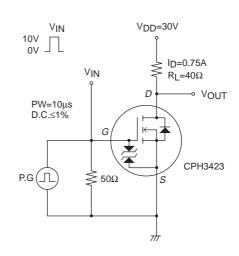
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.5A		4.8		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.5A		1.0		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.5A		1.0		nC
Diode Forward Voltage	VSD	IS=1.5A, VGS=0		0.89	1.2	V

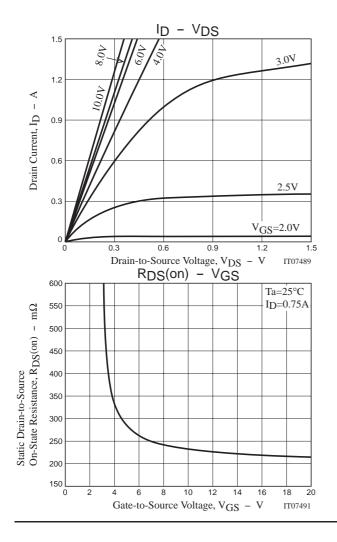
#### **Package Dimensions**

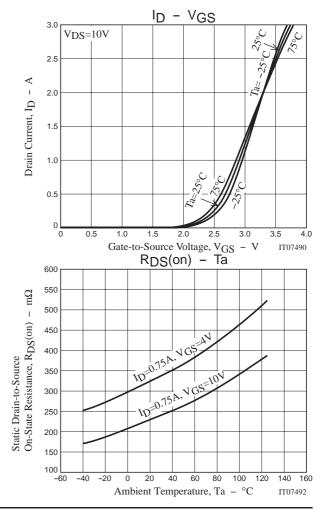
unit : mm 2152A

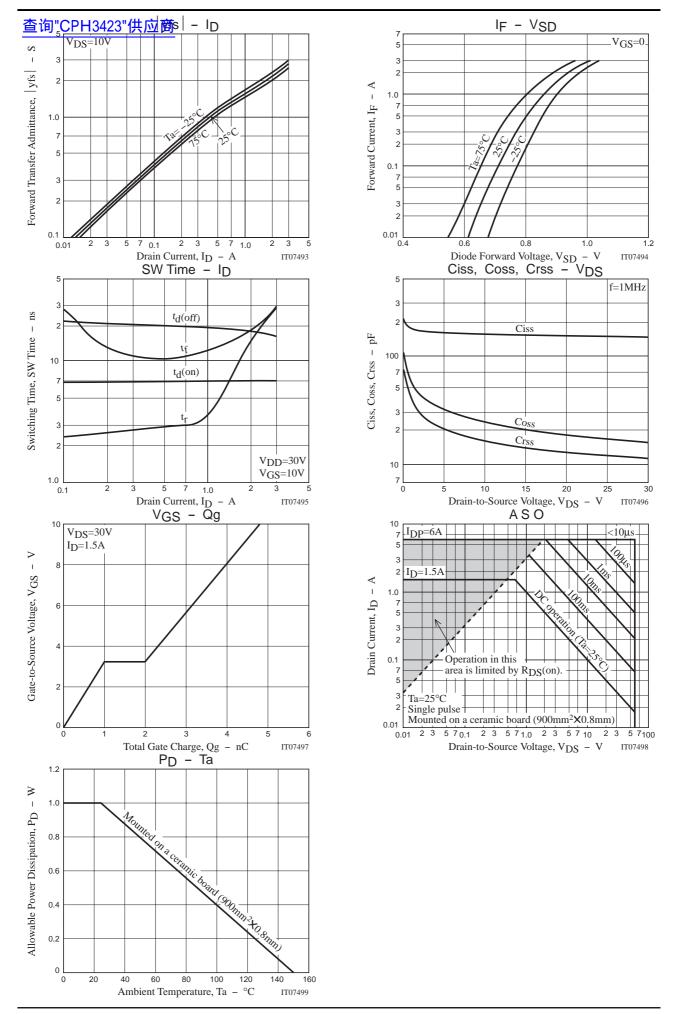


#### **Switching Time Test Circuit**









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Note on usage: Since the CPH3423 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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